



ZXTP25060BFH

60V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features and Benefits

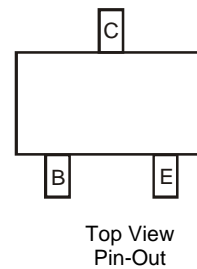
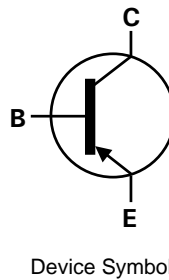
- $BV_{CEO} > -60V$ Breakdown Voltage
- 100V forward blocking voltage
- $I_C = -3A$ Continuous Collector Current,
- $I_{CM} = -9A$ Peak Pulse Current,
- Low saturation voltage, $V_{CE(sat)} < -85mV @ -1A$
- $R_{CE(sat)} = 58 m\Omega$ for a low equivalent on-resistance
- 1.25W power dissipation using SuperSOT package
- Complementary part number ZXTN25060BFH
- **Lead Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free, Green Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT23
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

Applications

- MOSFET drivers
- Power switches
- Motor control

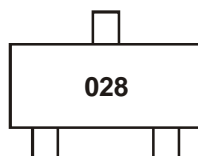


Ordering Information (Note 3)

Product	Case	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP25060BFHTA	SOT23	7	8mm	3000

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website at <http://www.diodes.com/>

Marking Information



028 = Product Type Marking Code

ZXTP25060BFH

Maximum Ratings @T_A = 25°C unless otherwise specified

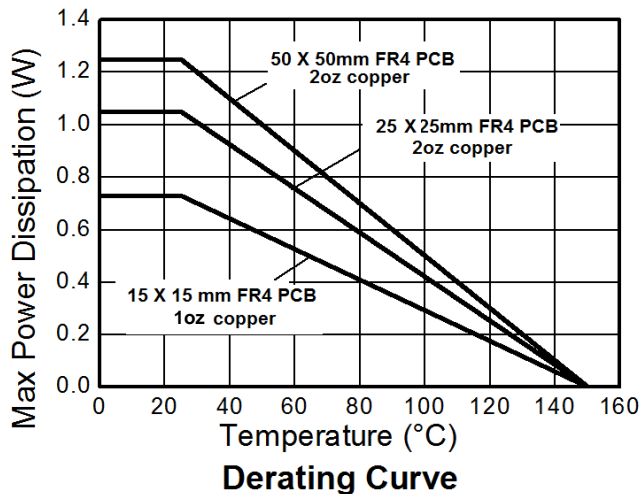
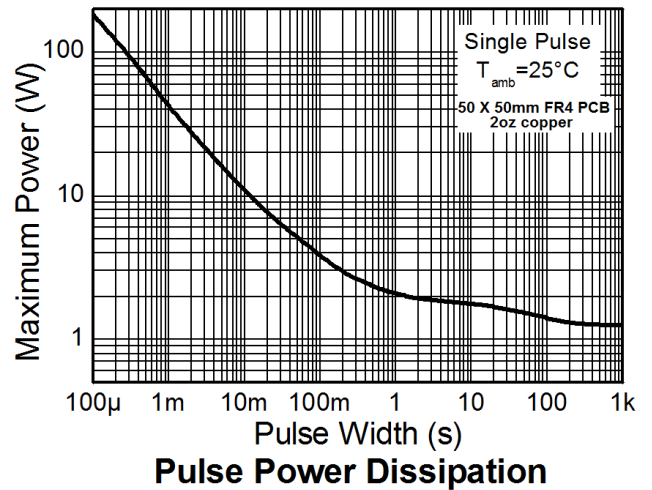
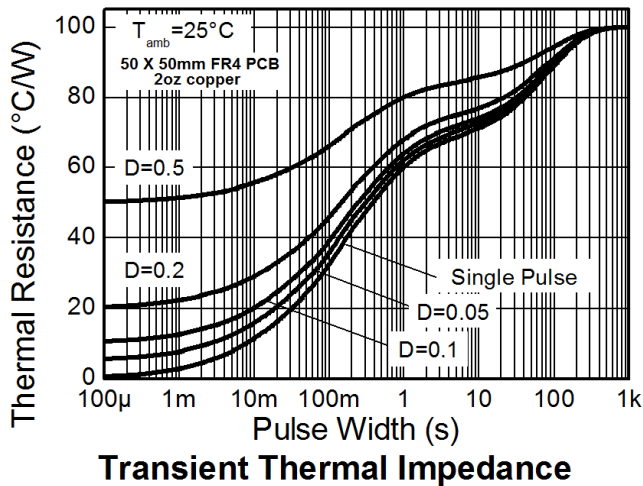
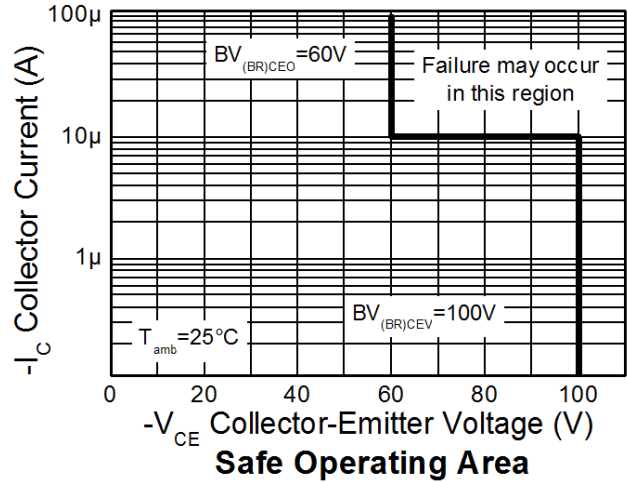
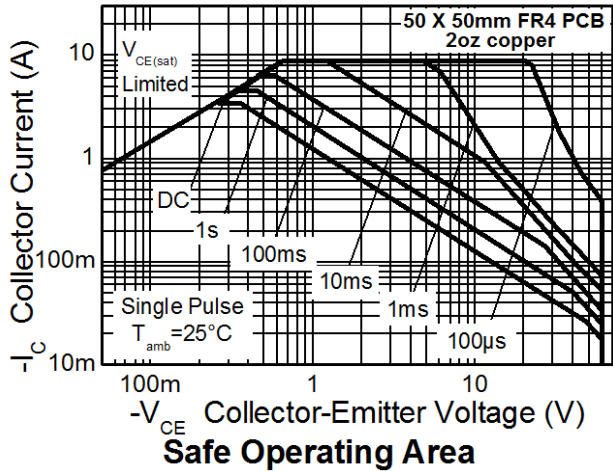
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-100	V
Collector-Emitter Voltage (forward blocking)	V _{CEX}	-100	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Collector Voltage (reverse blocking)	V _{ECO}	-7	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-3	A
Peak pulse Current	I _{CM}	-9	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation Linear derating factor	P _D	0.73	W
		5.84	
		1.05	
		8.4	
		1.25	
Thermal Resistance, Junction to Ambient	R _{θJA}	9.6	°C/W
		1.81	
		14.5	
		171	
Thermal Resistance, Junction to Ambient	R _{θJA}	119	°C/W
		100	
		69	
		74.95	
Thermal Resistance, Junction to Lead	R _{θJL}	74.95	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
4. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 5. Same as note (4), except the device is surface mounted on 25mm x 25mm with 2 oz copper.
 6. Same as note (4), except the device is surface mounted on 50mm x 50mm with 2 oz copper.
 7. Same as note (6), except the device is measured at t<5secs.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

Thermal Characteristics

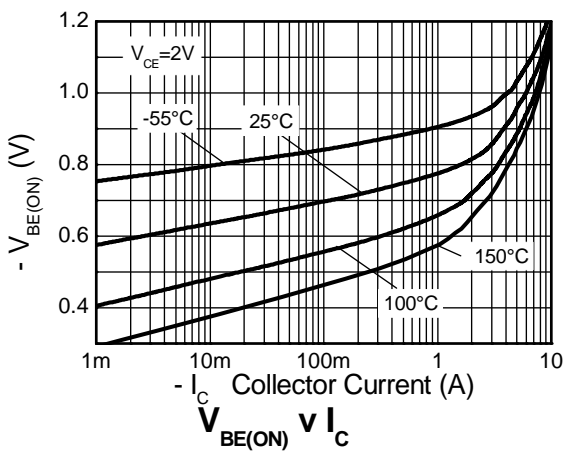
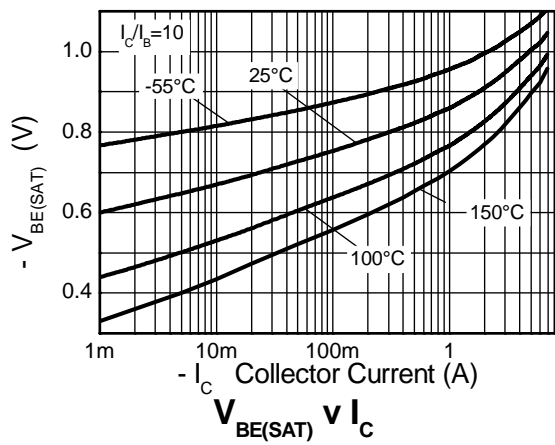
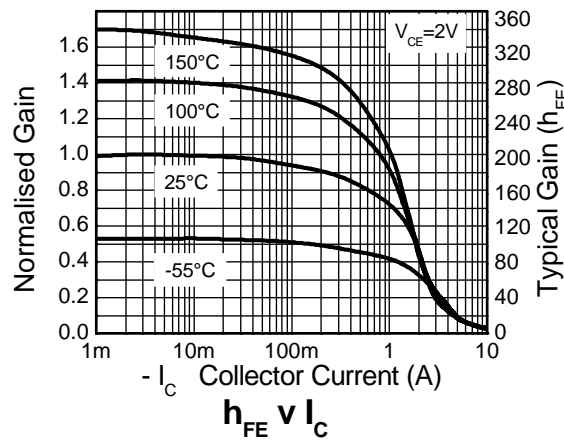
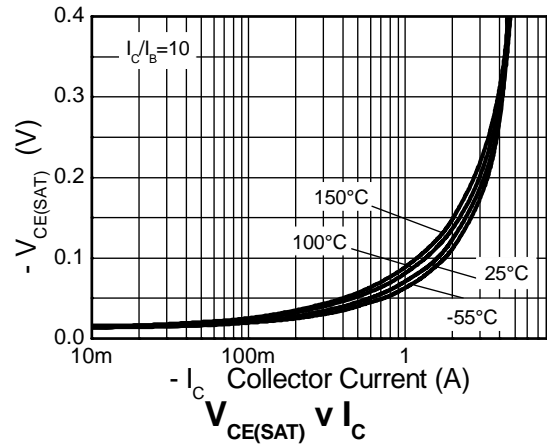
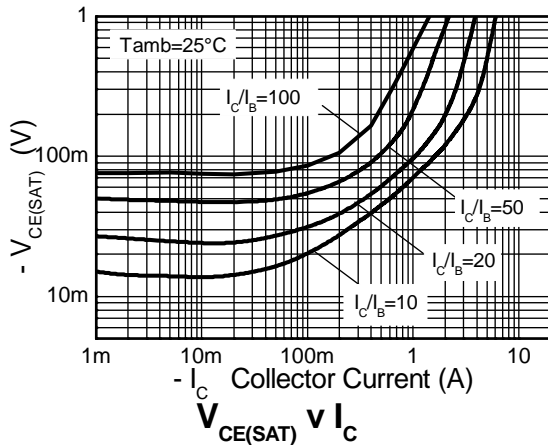


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-100	-120	-	V	I _C = -100 μA
Collector-Emitter Breakdown Voltage (forward blocking)	BV _{CEX}	-100	-120	-	V	I _C = -100 μA, R _{BE} < 1kΩ or -0.25V < V _{BE} < 1V
Collector-Emitter Breakdown Voltage (base open) (Note 9)	BV _{CEO}	-60	-80	-	V	I _C = -10mA
Emitter- Collector Breakdown Voltage (Reverse blocking) (Note 9)	BV _{ECO}	-7	-8.6	-	V	I _E = -100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	-	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	-	< -1	-50	nA	V _{CB} = -80V
		-	-	-20	μA	V _{CB} = -80V, T _A = 100°C
Collector emitter Cutoff Current	I _{CEX}	-	-	-100	nA	V _{CE} = -80V, R _{BE} < 1kΩ or -0.25V < V _{BE} < 1V
Emitter Cutoff Current	I _{EBO}	-	< -1	-50	nA	V _{EB} = -6V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	100	200	300	-	I _C = -10mA, V _{CE} = -2V
		75	150	-	-	I _C = -1A, V _{CE} = -2V
		30	60	-	-	I _C = -3A, V _{CE} = -2V
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	-940	-1040	mV	I _C = -3A, I _B = -300mA
Base-Emitter turn-on Voltage (Note 9)	V _{BE(on)}	-	-830	-930	mV	I _C = -3A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	-	-45	-55	mV	I _C = -0.5A, I _B = -50mA
		-	-100	-135		I _C = -0.5A, I _B = -10mA
		-	-70	-85		I _C = -1A, I _B = -100mA
		-	-175	-235		I _C = -3A, I _B = -300mA
Transition Frequency	f _T	-	250	-	MHz	I _C = -100mA, V _{CE} = -5V, f = 100MHz
Collector Output Capacitance (Note 9)	C _{OBO}	-	17.6	30	pF	V _{CB} = -10V, f = 1MHz
Turn-on time	t _(on)	-	26.5	-	ns	V _{CC} = -10V, I _C = -500mA,
Turn-off time	t _(off)	-	291	-	ns	I _{B1} = I _{B2} = -50mA

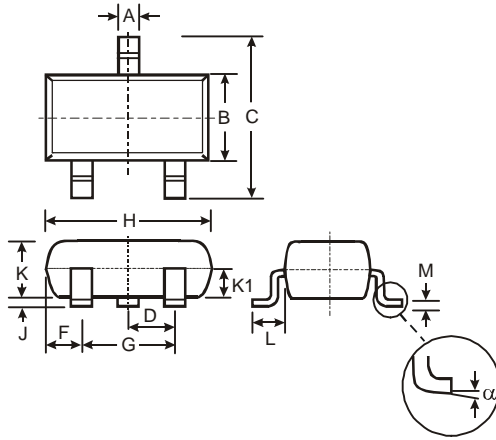
Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%

Typical Characteristics



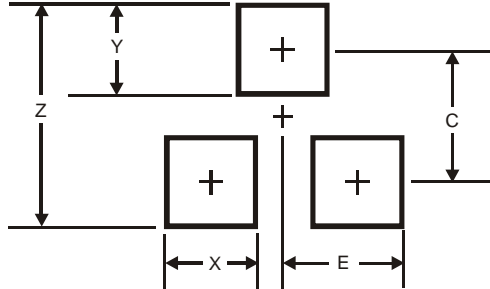
ZXTP25060BFH

Package Outline Dimensions



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2012, Diodes Incorporated

www.diodes.com

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru